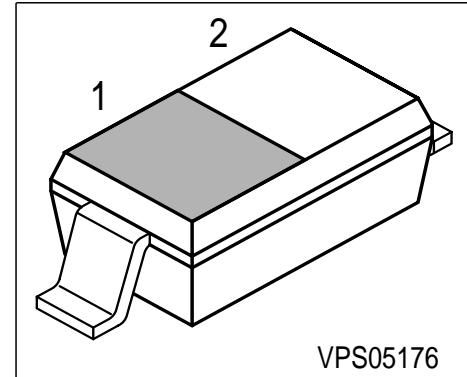


## Silicon Tuning Diode

- Extended frequency range up to 2.5 GHz;  
special design for use in TV-sat indoor units
- High capacitance ratio



| Type  | Marking | Pin Configuration |       | Package |
|-------|---------|-------------------|-------|---------|
| BB833 | white X | 1 = C             | 2 = A | SOD323  |

### Maximum Ratings

| Parameter                                  | Symbol    | Value       | Unit               |
|--|-----------|-------------|--------------------|
| Diode reverse voltage                      | $V_R$     | 30          | V                  |
| Peak reverse voltage ( $R \geq 5k\Omega$ ) | $V_{RM}$  | 35          |                    |
| Forward current                            | $I_F$     | 20          | mA                 |
| Operating temperature range                | $T_{op}$  | -55 ... 150 | $^{\circ}\text{C}$ |
| Storage temperature                        | $T_{stg}$ | -55 ... 150 |                    |

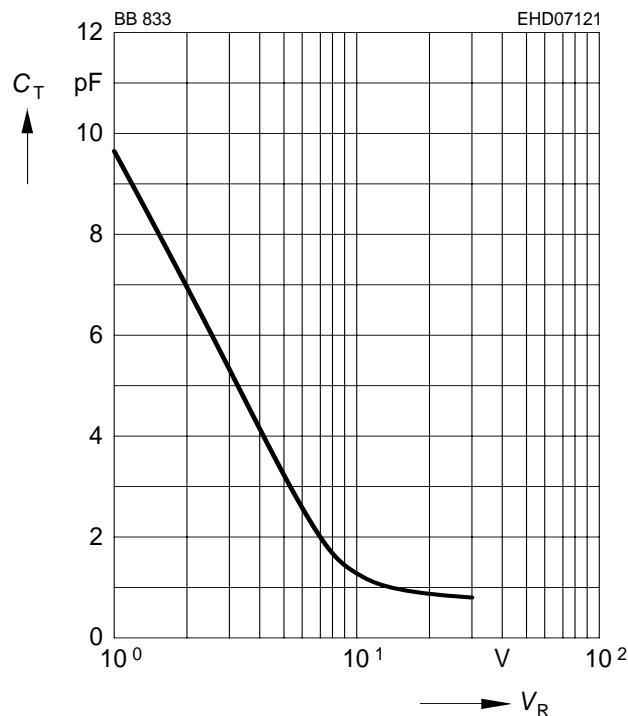
**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

| Parameter  | Symbol           | Values     |             |           | Unit     |
|--|------------------|------------|-------------|-----------|----------|
|  |                  | min.       | typ.        | max.      |          |
| <b>DC characteristics</b>  |                  |            |             |           |          |
| Reverse current<br>$V_R = 30 \text{ V}$  | $I_R$            | -          | -           | 20        | nA       |
| Reverse current<br>$V_R = 30 \text{ V}, T_A = 85^\circ\text{C}$  | $I_R$            | -          | -           | 500       |          |
| <b>AC characteristics</b>  |                  |            |             |           |          |
| Diode capacitance<br>$V_R = 1 \text{ V}, f = 1 \text{ MHz}$<br>$V_R = 28 \text{ V}, f = 1 \text{ MHz}$ | $C_T$            | 8.5<br>0.6 | 9.3<br>0.75 | 10<br>0.9 | pF       |
| Capacitance ratio<br>$V_R = 1 \text{ V}, V_R = 28 \text{ V}, f = 1 \text{ MHz}$                        | $C_{T1}/C_{T28}$ | 11         | 12.4        | -         | -        |
| Capacitance matching<br>$V_R = 1 \text{ V}, V_R = 28 \text{ V}, f = 1 \text{ MHz}$                     | $\Delta C_T/C_T$ | -          | -           | 3         | %        |
| Series resistance<br>$V_R = 1 \text{ V}, f = 470 \text{ MHz}$  | $r_s$            | -          | 1.8         | -         | $\Omega$ |
| Series inductance  | $L_s$            | -          | 1.8         | -         | nH       |

1) In-line matching. For details please refer to Application Note 047

**Diode capacitance  $C_T = f(V_R)$**

$f = 1\text{MHz}$



**Temperature coefficient of the diode capacitance  $T_{CC} = f(V_R)$**

$T_{CC}$  is plotted on a logarithmic scale from 10<sup>-5</sup> to 10<sup>-3</sup>  $^{\circ}\text{C}$ .

